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Determining Sensor Resolution

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MEMS-Based Tuning Fork Gyroscope

[Zaman, Ayazi, et al, MEMS'06]

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Drive Axis Equivalent Circuit

• Generates drive displacement velocity \dot{x}_d to which the Coriolis force is proportional

To Sense Amplifier (for synchronization)

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Drive-to-Sense Transfer Function

Rotation-Induced Coriolis Force:

$$\vec{a}_c = 2\vec{\omega}_d \times \vec{\Omega} = 2\omega_d \hat{x}_d \times \hat{\Omega}$$

\Rightarrow Acts in the sense mode direction

$$a_s = 2\omega_d x_d \Omega \sin 90^\circ$$

$\Rightarrow a_s = 2\omega_d x_d \Omega$

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Gyro Readout Equivalent Circuit (for a single tine)

Noise Sources

$\vec{F}_c = m\vec{a}_c = m \cdot (2\vec{\dot{x}}_d \times \vec{\Omega})$

Gyro Sense Element Output Circuit

Signal Conditioning Circuit (Transresistance Amplifier)

- Easiest to analyze if all noise sources are summed at a common node

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Minimum Detectable Signal (MDS)

- Minimum Detectable Signal (MDS):** Input signal level when the signal-to-noise ratio (SNR) is equal to unity

- The sensor scale factor is governed by the sensor type
- The effect of noise is best determined via analysis of the equivalent circuit for the system

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Move Noise Sources to a Common Point

- Move noise sources so that all sum at the input to the amplifier circuit (i.e., at the output of the sense element)
- Then, can compare the output of the sensed signal directly to the noise at this node to get the MDS

Sensor

Signal Conditioning Circuit

Output (Includes desired output plus noise)

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Gyro Readout Equivalent Circuit (for a single tine)

$\vec{F}_c = m\vec{a}_c = m \cdot (2\dot{\vec{x}}_d \times \vec{\Omega})$

Noise Sources

Gyro Sense Element Output Circuit

Signal Conditioning Circuit (Transresistance Amplifier)

- Here, v_{eq}^2 and i_{eq}^2 are equivalent input-referred voltage and current noise sources

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Noise

Noise

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Noise

- Noise:** Random fluctuation of a given parameter $I(t)$
- In addition, a noise waveform has a zero average value
- We can't handle noise at instantaneous times
- But we can handle some of the averaged effects of random fluctuations by giving noise a power spectral density representation
- Thus, represent noise by its mean-square value:

Let $i(t) = I(t) - I_D$

Then $\overline{i^2} = \overline{(I - I_D)^2} = \lim_{T \rightarrow \infty} \frac{1}{T} \int_0^T |I - I_D|^2 dt$

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Noise Spectral Density

- We can plot the spectral density of this mean-square value:

$\frac{\overline{i^2}}{\Delta f}$ [units²/Hz]

One-sided spectral density
 → used in circuits
 → measured by spectrum analyzers

Two-sided spectral density
 (1/2 the one-sided)

Often used in systems courses

$\overline{i^2}$ = integrated mean-square noise spectral density over all frequencies (area under the curve)

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Circuit Noise Calculations

Inputs: $v_i(j\omega)$ (Deterministic), $S_i(\omega)$ (Random)

Outputs: $v_o(j\omega)$ (Deterministic), $S_o(\omega)$ (Random)

System: Linear Time-Invariant System $H(j\omega)$

Mean square spectral density: $S_o(\omega)$

Root mean square amplitudes: $\sqrt{S_o(\omega)} = |H(j\omega)| \sqrt{S_i(\omega)}$

Handwritten notes: "No j-noise near random phase, so j is pointless!"

- Deterministic:** $v_o(j\omega) = H(j\omega)v_i(j\omega)$
- Random:** $S_o(\omega) = [H(j\omega)H^*(j\omega)]S_i(\omega) = |H(j\omega)|^2 S_i(\omega)$

How is it we can do this?

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Handling Noise Deterministically

Can do this for noise in a tiny bandwidth (e.g., 1 Hz)

$\frac{v_{n1}^2}{\Delta f} = S_1(f) \rightarrow v_{n1} = \sqrt{S_1(f) \cdot B}$

Can approximate this by a sinusoidal voltage generator (especially for small B, say 1 Hz)

Block Diagram: $S_n(j\omega)$ → Filter (Bandwidth B) → $v_o(t) = |A| \cos \omega_o t$

$\tau \sim \frac{1}{B}$

[This is actually the principle by which oscillators work → oscillators are just noise going through a tiny bandwidth filter]

Why? Neither the amplitude nor the phase of a signal can change appreciably within a time period $1/B$.

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Systematic Noise Calculation Procedure

General Circuit With Several Noise Sources

- Assume noise sources are uncorrelated
- 1. For i_{n1}^2 replace w/ a deterministic source of value $i_{n1} = \sqrt{\frac{i_{n1}^2}{\Delta f}} \cdot (1 \text{ Hz})$

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Systematic Noise Calculation Procedure

- Calculate $v_{on1}(\omega) = i_{n1}(\omega)H(j\omega)$ (treating it like a deterministic signal)
- Determine $v_{on1}^2 = i_{n1}^2 \cdot |H(j\omega)|^2$
- Repeat for each noise source: $i_{n1}^2, v_{n2}^2, v_{n3}^2$
- Add noise power (mean square values)

$$v_{onTOT}^2 = v_{on1}^2 + v_{on2}^2 + v_{on3}^2 + v_{on4}^2 + \dots$$

$$v_{onTOT} = \sqrt{v_{on1}^2 + v_{on2}^2 + v_{on3}^2 + v_{on4}^2 + \dots}$$

Total rms value

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Determining Sensor Resolution

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Example: Gyro MDS Calculation

$\vec{F}_c = m\vec{a}_c = m \cdot (2\dot{\vec{x}}_d \times \vec{\Omega})$

- The gyro sense presents a large effective source impedance
- Currents are the important variable; voltages are "opened" out
- Must compare i_o with the total current noise i_{eqTOT} going into the amplifier circuit

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Example: Gyro MDS Calculation (cont)

$\vec{F}_c = m\vec{a}_c = m \cdot (2\dot{\vec{x}}_d \times \vec{\Omega})$

• First, find the rotation to i_o transfer function:

$$\dot{x}_s = \frac{\omega_s Q}{k_s} \Theta(j\omega_d) F_s = \frac{\omega_s Q}{k_s} \cdot 2\omega_d \chi_d \Omega m \cdot \Theta(j\omega_d)$$

$[F_s = F_c = 2\omega_d \chi_d \Omega m]$

$$\dot{x}_s = 2 \frac{\omega_d}{\omega_s} Q \chi_d \Theta(j\omega_d) \cdot \Omega$$

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Example: Gyro MDS Calculation (cont)

$i_o = \eta_e \dot{x}_s = 2 \frac{\omega_d}{\omega_s} Q \chi_d \eta_e \Theta(j\omega_d) \cdot \Omega \rightarrow i_o = A \Omega$

$A \triangleq \text{scale factor}$

Where $A = 2 \frac{\omega_d}{\omega_s} Q \chi_d \eta_e \Theta(j\omega_d)$

When $\Omega = \Omega_{min} \triangleq \text{MDS}$, $i_o = i_{eqTOT}$ ← input-referred noise current entering the sense amplifier → in pA/√Hz

$\therefore i_{eqTOT} = A \Omega_{min} \rightarrow \Omega_{min} = \frac{i_{eqTOT} (\frac{3600s}{hr}) (\frac{180^\circ}{\pi})}{A} [(\%hr)/\sqrt{Hz}]$

Angle Random Walk: $ARW = \frac{1}{\delta \Omega} \Omega_{min} [^\circ/\sqrt{hr}]$

← Earlier to determine directional error as a function of elapsed time.

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Example: Gyro MDS Calculation (cont)

$\vec{F}_c = m\vec{a}_c = m \cdot (2\dot{\vec{x}}_d \times \vec{\Omega})$

Now, find the i_{eqTOT} entering the amplifier input:

$$i_{eqTOT}^2 = i_s^2 + i_{eq}^2 \rightarrow i_{eqTOT}^2 = i_s^2 + i_f^2 + i_a^2 + \frac{N_{ia}^2}{R_f^2}$$

$i_s^2 = 4kTR_x$ (Brownian motion noise of the sense element)

→ determined entirely by the noise in $r_x \rightarrow f_{r_x}^2$

→ easiest to convert to an all electrical equiv. ckt.

Example: Gyro MDS Calculation (cont)

$N_{R_x}^2 = 4kTR_x$

Where $L_x = \frac{R_x}{\eta_c^2}$, $C_x = \eta_c^2 C_x$, $R_x = \frac{r_x}{\eta_c^2}$

$i_s^2 = N_{R_x} \left(\frac{1}{R_x} \right) |1 + j\omega d|^2 \rightarrow \frac{i_s^2}{\Delta f} = 4kTR_x \left(\frac{1}{R_x} \right) |1 + j\omega d|^2$

$\Rightarrow \frac{i_s^2}{\Delta f} = \frac{4kT}{R_x} |1 + j\omega d|^2$

Thus:

$$\frac{i_{eqTOT}^2}{\Delta f} = \frac{4kT}{R_x} |1 + j\omega d|^2 + \frac{4kT}{R_f} + \frac{i_a^2}{\Delta f} + \frac{N_{ia}^2}{R_f^2}$$

Learn to get these from EE240.
or just get them from a data sheet ...

LF356 Op Amp Data Sheet

LF155/LF156/LF256/LF257/LF355/LF356/LF357
JFET Input Operational Amplifiers

General Description

- Logarithmic amplifiers
- Photocell amplifiers
- Sample and Hold circuits

Common Features

- Low input bias current: 30pA
- Low Input Offset Current: 3pA
- High input impedance: $10^{12}\Omega$
- Low input noise current: $0.01 \text{ pA}/\sqrt{\text{Hz}}$
- High common-mode rejection ratio: 100 dB
- Large dc voltage gain: 106 dB

Features

Advantages

- Replace expensive hybrid and module FET op amps
- Rugged JFETs allow blow-out free handling compared with MOSFET input devices
- Excellent for low noise applications using either high or low source impedance—very low 1/f corner
- Offset adjust does not degrade drift or common-mode rejection as in most monolithic amplifiers
- New output stage allows use of large capacitive loads (5,000 pF) without stability problems
- Internal compensation and large differential input voltage capability

Applications

- Precision high speed integrators
- Fast D/A and A/D converters
- High impedance buffers
- Wideband, low noise, low drift amplifiers

Uncommon Features

	LF155/ LF355	LF156/ LF256/ LF356 ($A_{v0}=5$)	LF257/ LF357	Units
Extremely fast settling time to 0.01%	4	1.5	1.5	μs
Fast slew rate	5	12	50	V/ μs
Wide gain bandwidth	2.5	5	20	MHz
Low input noise voltage	20	12	12	nV/ $\sqrt{\text{Hz}}$

Handwritten notes: $\frac{i_a^2}{\Delta f} = 0.01 \text{ pA}/\sqrt{\text{Hz}}$ and $\frac{N_{ia}^2}{\Delta f} = 12 \text{ nV}/\sqrt{\text{Hz}}$

Example ARW Calculation

Example Design:

Sensor Element:

- $m = (100\mu\text{m})(100\mu\text{m})(20\mu\text{m})(2300\text{kg}/\text{m}^3) = 4.6 \times 10^{-10} \text{ kg}$
- $\omega_s = 2\pi(15\text{kHz})$
- $\omega_d = 2\pi(10\text{kHz})$
- $k_s = \omega_s^2 m = 4.09 \text{ N/m}$
- $X_d = 20 \mu\text{m}$
- $Q_s = 50,000$
- $V_p = 5\text{V}$
- $h = 20 \mu\text{m}$
- $d = 1 \mu\text{m}$

Sensing Circuitry:

- $R_f = 100\text{k}\Omega$
- $i_a = 0.01 \text{ pA}/\sqrt{\text{Hz}}$
- $v_a = 12 \text{ nV}/\sqrt{\text{Hz}}$

Example ARW Calculation (cont)

Get rotation rate to output current scale factor:

$$A = 2 \frac{\omega_d}{\omega_s} Q_s \eta_e |\Phi(j\omega_d)| = 2 \left(\frac{10k}{15k} \right) (50k) (20\mu) (5) (2000\epsilon_0) (0.000024) = 2.83 \times 10^{-12} C$$

$$\Phi(j\omega_d) = \frac{(j\omega_d)(\omega_s/\omega_s)}{-\omega_d^2 + \frac{j\omega_d\omega_s}{Q_s} + \omega_s^2} = \frac{j(10k)(15k)/(15k)}{(15k)^2 - (10k)^2 + \frac{j(10k)(15k)}{50k}} = \frac{j(3k)}{1.25 \times 10^8 - j(3k)}$$

$$\rightarrow |\Phi(j\omega_d)| = \frac{3k}{\sqrt{(1.25 \times 10^8)^2 + (3k)^2}} = 0.000024 \quad 8.854 \times 10^{-8} F/m$$

$$\left[\frac{\partial C}{\partial x} = \frac{C_0}{d} = \frac{\epsilon_0 h \omega_p}{d} = \frac{\epsilon_0 (20\mu)(100\omega)}{(1\mu)^2} = 2000\epsilon_0 \rightarrow \eta_e = V_p \frac{\partial C}{\partial x} = 5(2000\epsilon_0) \right]$$

Assume electrode covers the whole sidewall. $8.854 \times 10^{-12} F/m$

Then, get noise:

$$\frac{\dot{i}_{eqTOT}^2}{\Delta f} = \frac{4kT}{R_x} |\Phi(j\omega_d)|^2 + \frac{4kT}{R_f} + \frac{\dot{i}_{ia}^2}{\Delta f} + \frac{\dot{N}_{Rf}^2}{\Delta f} \left(\frac{1}{R_f} \right)$$

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Example ARW Calculation (cont)

$$\left[R_x = \frac{\omega_s m}{Q_s^2 \epsilon} = \frac{2\pi(15k)(4.6 \times 10^{-10})}{(50k)(8.854 \times 10^{-8})} = 110.6 k\Omega \right]$$

$$\frac{\dot{i}_{eqTOT}^2}{\Delta f} = \frac{(1.66 \times 10^{-29})(0.000024)^2}{(110.6k)} + \frac{(1.66 \times 10^{-29})}{1M} + (0.01p)^2 + \frac{(12n)^2}{(1M)^2}$$

$8.64 \times 10^{-35} A^2/Hz$ $1.66 \times 10^{-26} A^2/Hz$ $1 \times 10^{-28} A^2/Hz$ $1.44 \times 10^{-28} A^2/Hz$
 sensor element noise Insignificant Noise from R_f dominates!

$$\therefore \frac{\dot{i}_{eqTOT}^2}{\Delta f} = 1.68 \times 10^{-26} A^2/Hz \rightarrow \dot{i}_{eqTOT} = \sqrt{\frac{\dot{i}_{eqTOT}^2}{\Delta f}} = 1.30 \times 10^{-13} A/\sqrt{Hz}$$

$$\therefore \Omega_{min} = \frac{\dot{i}_{eqTOT}}{A} \left(\frac{3600s}{hr} \right) \left(\frac{180^\circ}{\pi} \right) = \frac{1.30 \times 10^{-13}}{2.83 \times 10^{-12}} (3600) \left(\frac{180^\circ}{\pi} \right) = 9448 (\%/hr)/\sqrt{Hz}$$

And finally:

$$ARW = \frac{1}{60} \Omega_{min} = \frac{1}{60} (9448) = 157 \%/hr = ARW \Rightarrow \text{Almost turned around in 1 hour!}$$

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What if $\omega_d = \omega_s$?

If $\omega_d = \omega_s = 15k Hz$, then $|\Phi(j\omega_d)| = 1$ and

$$A = 2 \frac{\omega_d}{\omega_s} Q_s \eta_e |\Phi(j\omega_d)| = 2 Q_s \eta_e = 2(50k)(20\mu)(5)(2000\epsilon_0) = 1.77 \times 10^{-7} C$$

$$\frac{\dot{i}_{eqTOT}^2}{\Delta f} = \frac{(1.66 \times 10^{-29})(1)^2}{(110.6k)} + \frac{(1.66 \times 10^{-29})}{1M} + (0.01p)^2 + \frac{(12n)^2}{(1M)^2}$$

$1.51 \times 10^{-25} A^2/Hz$ $1.66 \times 10^{-26} A^2/Hz$ $1 \times 10^{-28} A^2/Hz$ $1.44 \times 10^{-28} A^2/Hz$
 Now, the sensor element dominates!

$$\therefore \frac{\dot{i}_{eqTOT}^2}{\Delta f} = 1.67 \times 10^{-25} A^2/Hz \rightarrow \dot{i}_{eqTOT} = \sqrt{\frac{\dot{i}_{eqTOT}^2}{\Delta f}} = 4.08 \times 10^{-13} A/\sqrt{Hz}$$

$$\therefore \Omega_{min} = \frac{\dot{i}_{eqTOT}}{A} \left(\frac{3600s}{hr} \right) \left(\frac{180^\circ}{\pi} \right) = \frac{4.08 \times 10^{-13}}{1.77 \times 10^{-7}} (3600) \left(\frac{180^\circ}{\pi} \right) = 0.476 (\%/hr)/\sqrt{Hz}$$

And finally:

$$ARW = \frac{1}{60} \Omega_{min} = \frac{1}{60} (0.476) = 0.0079 \%/hr = ARW \Rightarrow \text{Navigation grade!}$$

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